

Revised phase diagram of the high- T_c cuprate superconductor Pb-doped $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$ revealed by anisotropic transport measurements

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Although phase diagrams can be leveraged to investigate high transition temperature (high- T_c) superconductivity, the issue has not been discussed thoroughly. In this study, we elucidate the phase diagram of the overdoped side of high- T_c cuprates via systematic anisotropic transport measurements for Pb-doped Bi-2212 single crystals. We demonstrate that the characteristic temperatures of the “weak” pseudogap opening and electronic coherence cross each other at a critical doping level, while those of the “strong” pseudogap merges into that of superconducting fluctuations above the critical doping level. Our results indicate the importance of Mottness in high- T_c superconductivity.

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I. INTRODUCTION

Superconductivity is an instability of the normal metallic state. Therefore, understanding the normal state from which superconductivity emerges is crucial to probe the underlying mechanism of superconductivity [1]. The features of the normal state can be evaluated from the doping (p)-temperature (T) phase diagram. Two types of theoretical phase diagrams have been proposed for cuprates. The first is the quantum critical point (QCP) model [2,3], in which T^* (characteristic temperatures of pseudogap opening) and T_{coh} (crossover temperatures from the “strange metal” state at higher temperatures to the Fermi-liquid-like state at lower temperatures) vanish at the QCP [Fig. 1(a)]. Moreover, the fluctuations associated with the quantum critical phase transition mediate Cooper pairing. The second is the resonating valence bond (RVB) model [4–6]. Here, we evaluate the RVB model by considering the fluctuations of the gauge fields to which spinons and holons are strongly coupled, since these fluctuations affect charge dynamics such as transport properties [4–6]. In this model, spin gap opening temperature, T_D (or its mean-field solution, $T_D^{(0)}$), and Bose condensation temperature for holons, T_{BE} (or its mean-field solution, $T_{BE}^{(0)}$), which corresponds to T_{coh} cross each other at a finite temperature near optimal doping [Fig. 1(b)]. Here, large spin correlations arising from Mottness serve as the source for Cooper pairing. However, the level of accuracy of these two-phase diagrams has been debated upon in the literature [7].

The positional relationship between the pseudogap (or spin gap) opening temperatures and T_{coh} is unclear. In contrast to

the pseudogap opening temperature [1,8–11], the behavior of T_{coh} has rarely been reported [12–15], and a general consensus has not been obtained yet [7]. This can be attributed to the limited number of materials that can be examined. Pb-doped $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$ (Bi-2212) [hereafter we denote it as Bi(Pb)-2212] is a suitable choice for such an investigation because the doping levels can be controlled from an approximately optimal value to beyond the critical doping level $p = 0.19$ via oxygen annealing [16,17].

To this end, we first measured the anisotropic transport properties of Bi(Pb)-2212, and estimated the characteristic temperatures at which the typical temperature evolution occurs. $\rho_c(T)$ aids in identifying opening energy gaps, since it directly probes the electronic DOS around the Fermi level, reflecting the tunneling nature between CuO_2 planes in high- T_c cuprates [18–20]. Furthermore, $\rho_{ab}(T)$ is less sensitive to opening energy gaps [20–22], but is sensitive to electronic coherence [13,14] and superconducting fluctuations [20]. Systematic measurements of both $\rho_{ab}(T)$ and $\rho_c(T)$ for the same set of samples aid in obtaining the true phase diagram of overdoped Bi(Pb)-2212. The obtained phase diagram shows that (i) two types (“weak” and “strong”) of pseudogaps exist, (ii) they terminate at different p 's, and (iii) the characteristic temperatures of the weak pseudogap opening and T_{coh} intersect. Finally, we discuss the implications of the obtained phase diagram.

II. EXPERIMENT

Single crystals of $\text{Bi}_{1.6}\text{Pb}_{0.4}\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$ (nominal composition of $\text{Bi}_{1.6}\text{Pb}_{0.6}\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$) were grown in air using the traveling solvent floating zone method. The crystals were annealed by varying the oxygen partial pressure P_{O_2}

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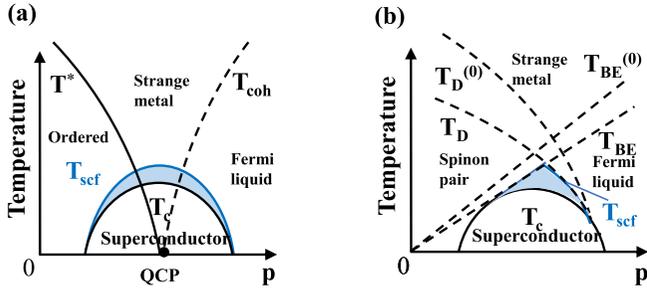


FIG. 1. Schematic phase diagrams for (a) a QCP model [2,3] and (b) an RVB model considering gauge field fluctuations [4–6]. In each figure, the black bold lines denote the true phase transition temperatures, whereas the black dashed lines denote the crossover temperatures. The blue shaded area denotes the superconducting fluctuation regime. Here, the original phase transition temperatures of the RVB model are represented by T_{scf} , considering the strong two-dimensionality of cuprates.

($2 \text{ Pa} \leq P_{O_2} \leq 400 \text{ atm}$), at 400–600 °C for sufficient durations to homogeneously control the corresponding doping levels (for detailed annealing conditions, see the Supplemental Material [23]). Moreover, previously reported data for excessively overdoped ($p = 0.232$) pristine samples [20] were included in the analysis. We determined T_c at the onset of zero resistivity. The doping level (p) was obtained using the empirical relation [24], with maximum $T_c = 91.7 \text{ K}$ and 91.0 K for Pb-doped single crystals and pristine samples, respectively.

$\rho_{ab}(T)$ and $\rho_c(T)$ were measured using the DC four-terminal method. In addition, to estimate the characteristic temperature for the superconducting fluctuation, T_{scf} , below which the superconducting fluctuation effect becomes appreciable, $\rho_{ab}(T)$ was measured using a physical property measurement system (Quantum Design) under various magnetic fields up to 9 T parallel to the c axis. Moreover, to examine the temperature dependence of the Hall mobility, $\mu(T) [=R_H(T)/\rho_{ab}(T)]$, the Hall coefficient $R_H(T)$ was measured via the five-terminal method. Here, $R_H [= \rho_{yx}(B)/B]$ was obtained by averaging the difference of the Hall resistivity ρ_{yx} at positive and negative fields B , i.e., $\rho_{yx}(B) = [\rho_{yx}(+B) - \rho_{yx}(-B)]/2$, which can eliminate the magnetoresistance (MR) component due to the misalignment of contacts.

III. RESULTS

Figure 2 shows the temperature dependence of $\rho_{ab}(T)$ for $\text{Bi}_{1.6}\text{Pb}_{0.4}\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$ single crystals with various p . T_c decreases systematically from 89.3 to 65.0 K (52.0 K for the pristine sample) with increasing oxygen content, indicating that the measured samples are in the overdoped region. In the slightly overdoped region ($0.177 \leq p \leq 0.191$), $\rho_{ab}(T)$ is approximately linear in T , which is consistent with a previous report [21]. However, by further increasing the doping level, $\rho_{ab}(T)$ exhibits a typical upward curvature.

To investigate the temperature dependence of $\rho_{ab}(T)$ in detail, its derivative with respect to temperature for several values of p is plotted as a function of the temperature in Fig. 3(a). At higher temperatures, the derivative is approximately linear in T , whereas below the temperature region

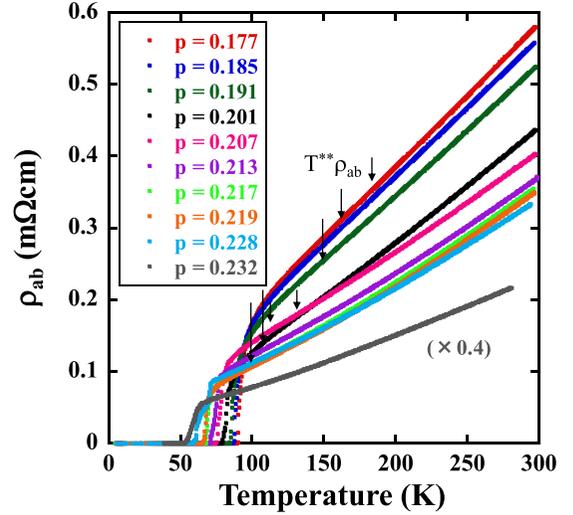


FIG. 2. In-plane resistivity $\rho_{ab}(T)$ for $\text{Bi}_{1.6}\text{Pb}_{0.4}\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$ single crystals with various p . The most overdoped sample with $p = 0.232$ is pristine $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$ [20]. The temperatures $T_{\rho_{ab}}^{**}$ below which $\rho_{ab}(T)$ decreases rapidly are indicated by arrows.

180–100 K, it exhibits a steep upward curvature, reflecting a steep decrease in $\rho_{ab}(T)$ upon cooling. Here, we define the characteristic temperature at which the temperature derivative of $\rho_{ab}(T)$ is minimized as $T_{\rho_{ab}}^{**}$. $T_{\rho_{ab}}^{**}$ is estimated as 160, 150, 130, and 102 K for $p = 0.185, 0.191, 0.201,$ and 0.219 , respectively. $T_{\rho_{ab}}^{**}$ may correspond to T_{scf}^* , which was previously defined for underdoped Bi-2212 [20,21].

The high-temperature T -linear behavior of the temperature derivative of $\rho_{ab}(T)$ indicates that $\rho_{ab}(T)$ can be expressed as [13,25]

$$\rho_{ab}(T) = \alpha_0 + \alpha_1 T + \alpha_2 T^2, \quad (1)$$

where α_0 is the residual resistivity, α_1 is the coefficient of the non-Fermi-liquid T -linear term, and α_2 is the coefficient of the Fermi-liquid T^2 term. The slope and y intercept of $d\rho_{ab}/dT$ represent $2\alpha_2$ and α_1 , respectively. However, a closer look at the data reveals that the slope below 200 K is slightly larger than that above 200 K. Thus, the coefficients are obtained below and above 200 K separately by the linear fits [Fig. 3(a); for more information on the linear fits, see the Supplemental Material [23]], and are denoted as $\alpha_1(0), \alpha_2(0)$ and $\alpha_1(\infty), \alpha_2(\infty)$, respectively. The rise (fall) in $\alpha_2(\alpha_1)$ upon cooling implies that the electronic state approximates that of Fermi liquids in the lower temperature region. Based on this, $T_{coh}\rho_{ab}$ is defined by the temperature at which both linearly fitted lines intersect. As expected, $T_{coh}\rho_{ab}$ is estimated to be approximately 200 K for all doping levels [Fig. 3(a)].

However, it should be noted that the change above and below $T_{coh}\rho_{ab}$ is insignificant for $p < 0.19$ (see the Supplemental Material [23]). The reason will be discussed later in the final paragraph of Sec. IV. Furthermore, the slope of $d\rho_{ab}/dT$ is finite for all p , indicating that $\rho_{ab}(T)$ is not strictly T linear even in the higher temperature region. This result is different from the typical behaviors for the “strange metal” state [2,3], and from previous reports on Bi-2212 [12], $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$ (LSCO) [13], and $\text{Tl}_2\text{Ba}_2\text{CuO}_{6+\delta}$ (Tl-2201) [14]. However,

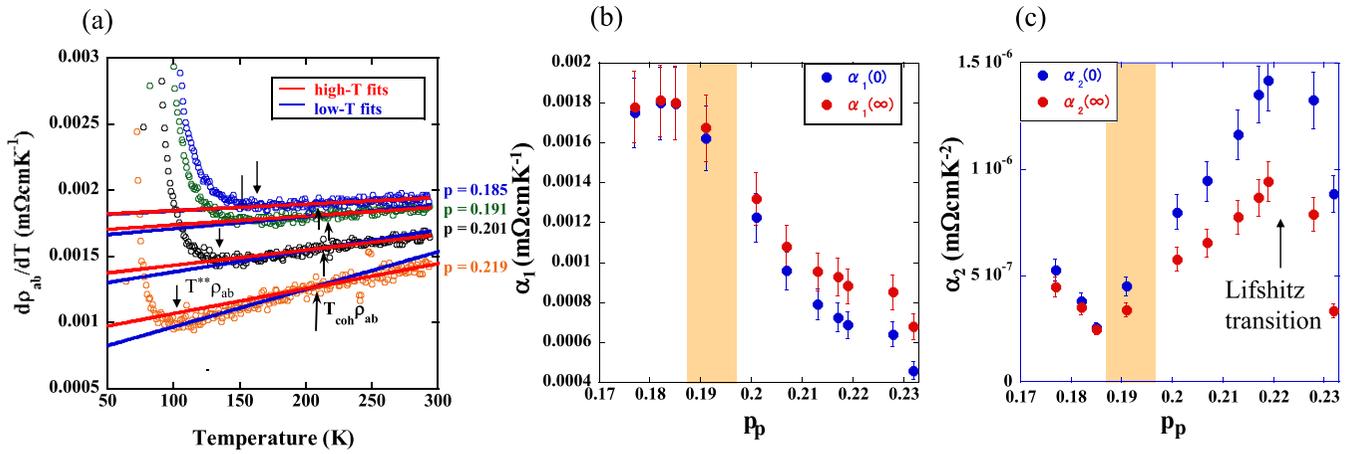


FIG. 3. (a) Temperature derivative of ρ_{ab} vs temperature for several p . The temperatures $T_{\rho_{ab}}^{**}$ at which $d\rho_{ab}/dT$ is minimum and $T_{\text{coh}\rho_{ab}}$ at which high-temperature and low-temperature linear fits intersect are indicated by arrows. (b) The coefficient of the T -linear term in $\rho_{ab}(T)$, α_1 , vs p . $\alpha_1(\infty)$ and $\alpha_1(0)$ is obtained by the linear fits for $d\rho_{ab}/dT$ at high and low temperatures, respectively. (c) The coefficient of the T^2 term in $\rho_{ab}(T)$, α_2 , vs p . $\alpha_2(\infty)$ and $\alpha_2(0)$ is obtained by the linear fits for $d\rho_{ab}/dT$ at high and low temperatures, respectively.

this result agrees with $\text{Bi}_2\text{Sr}_{2-x}\text{La}_x\text{CuO}_6$ (BSLCO) [26], in which a finite slope in $d\rho_{ab}/dT$ has been observed for La content $x = 0.24$ and 0.30 .

Figures 3(b) and 3(c) depict the doping level dependence of α_1 and α_2 , respectively. Upon increasing the doping level to above 0.19, α_1 (α_2) decreases (increases), implying that the system acquires a Fermi-liquid-like nature over this doping level range. This result is consistent with recent ARPES measurements of $\text{Bi}(\text{Pb})$ -2212, which reveal that with the increasing doping level across $p = 0.19$, the incoherent spectral function abruptly reconstructs into a coherent one near the Brillouin zone boundary [17]. The decrease in $\alpha_1(0)$ for $p > 0.19$ is consistent with previous reports for LSCO [13,25] and Tl-2201 [14]. However, with a further increase in the doping level, α_2 exhibits a peak at approximately $p = 0.22$. This may be related to the reported Lifshitz transition at $p = 0.22$, where the Fermi surface originating from the antibonding states changes its topology from an open holelike state to a closed electronlike state [27,28]. The Van Hove singularity then crosses the Fermi level, which causes a peak in the specific heat coefficient γ . The observed peak in α_2 may be attributed to the empirical fact that the Kadowaki-Woods ratio α_2/γ^2 is maintained constant within the same series of compounds [29,30]. In addition, we find that the difference between $\alpha_1(0)$ [$\alpha_2(0)$] and $\alpha_1(\infty)$ [$\alpha_2(\infty)$] is expanded continuously for $p \geq 0.19$. This implies that the system becomes more Fermi-liquid-like below $T_{\text{coh}\rho_{ab}}$ with an increase in the doping level.

Figure 4(a) shows the temperature dependence of the out-of-plane resistivity $\rho_c(T)$ for $\text{Bi}_{1.6}\text{Pb}_{0.4}\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$ single crystals with various p . The most overdoped sample ($p = 0.232$) is pristine $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$. Although $\rho_c(T)$ exhibits metallic behavior above 250 K, the gradual upturn below a certain temperature $T_{\rho_c}^*$ is an indication of the opening of the pseudogap [18–21] (hereafter referred to as “weak” pseudogap [1]). $T_{\rho_c}^*$ is determined using a previously reported definition [18,20,21]. $T_{\rho_c}^*$ is high even for $p > 0.19$ but decreases rapidly when p exceeds 0.22. However, $T_{\rho_c}^*$ cannot be determined above T_c at $p = 0.232$ [Fig. 4(b)]. At temperatures

below $T_{\rho_c}^*$, $\rho_c(T)$ increases rapidly below $T_{\rho_c}^{**}$. This suggests that another pseudogap (hereafter referred to as “strong” pseudogap [1]) opens up below this temperature. $T_{\rho_c}^{**}$ is estimated as 198, 189, 178, 176, 153, 129, 101, and 90 K for $p = 0.160, 0.179, 0.183, 0.185, 0.192, 0.200, 0.213,$ and 0.216 , respectively. Here, $T_{\rho_c}^{**}$ is defined as the temperature at which $\rho_c(T)$ is minimized. $T_{\rho_c}^{**}$ cannot be determined for $p \geq 0.221$, because the rapid increase is not observed in these samples.

To investigate the relationship between the weak and strong pseudogap opening temperatures and T_{scf} , T_{scf} was estimated by comparing the values of $\rho_{ab}(T)$ with and without a magnetic field. Figures 5(a)–5(d) show $\rho_{ab}(T)$ under various magnetic fields up to 9 T for the samples with $p = 0.179, 0.194, 0.206,$ and 0.220 , respectively. The temperature dependence of the normal state reproduces the features shown in Fig. 2 well. In the superconducting state, a typical fan-shaped broadening under the magnetic fields due to the suppression of the Aslamazov-Larkin type superconducting fluctuation effect in strongly two-dimensional superconductors [31–33] was observed. The expanded plots near T_c are shown in the insets to Figs. 6(a)–6(d). Since the largest field, 9 T, was most effective in suppressing the superconducting fluctuation effect, we depict the temperature derivative of $\rho_{ab}(T)$ at 0 and 9 T as a function of the temperature for each doping level in Figs. 6(a)–6(d). In all figures, the data plots at 9 T deviate from those at 0 T below a certain temperature T_{scf} , indicating that the superconducting fluctuation effect manifests below these temperatures. Based on this, T_{scf} is defined as the temperature at which $d\rho_{ab}(T)/dT$ under a magnetic field of 9 T decreases by 1%, relative to that at 0 T. Consequently, T_{scf} is estimated as 119, 113, 97, and 86 K for $p = 0.179, 0.194, 0.206,$ and 0.220 , respectively. This result is consistent with our previous study on Bi-2212 [20]. T_{scf} for $p = 0.232$ was previously estimated as 73 K [20].

To obtain further insight into the occurrence of incoherent to coherent crossover transition, we measured $R_H(T)$ for the same samples shown in Figs. 5(a)–5(d). The results are shown in Fig. 7. The ρ_{yx} was positive and linear in B within the temperature range measured. The magnitude of $R_H(T)$ decreases

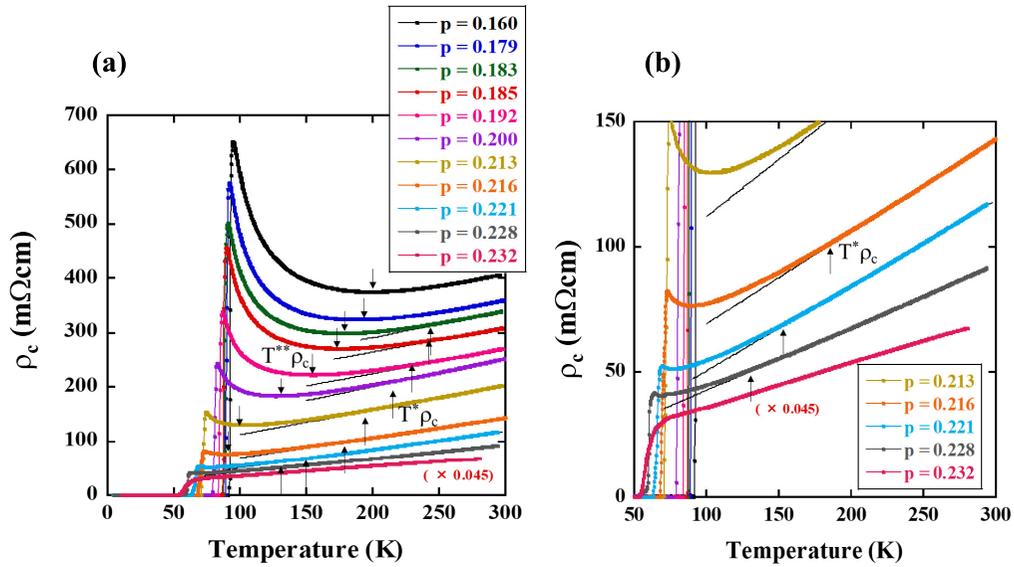


FIG. 4. (a) Out-of-plane resistivity $\rho_c(T)$ for $\text{Bi}_{1.6}\text{Pb}_{0.4}\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$ single crystals with various p . The most overdoped sample with $p = 0.232$ is pristine $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$ [20]. The temperatures $T^*_{\rho_c}$ below which $\rho_c(T)$ gradually increases and $T^{**}_{\rho_c}$ at which $\rho_c(T)$ is minimized are indicated by arrows. (b) Expanded view of the overdoped side of (a).

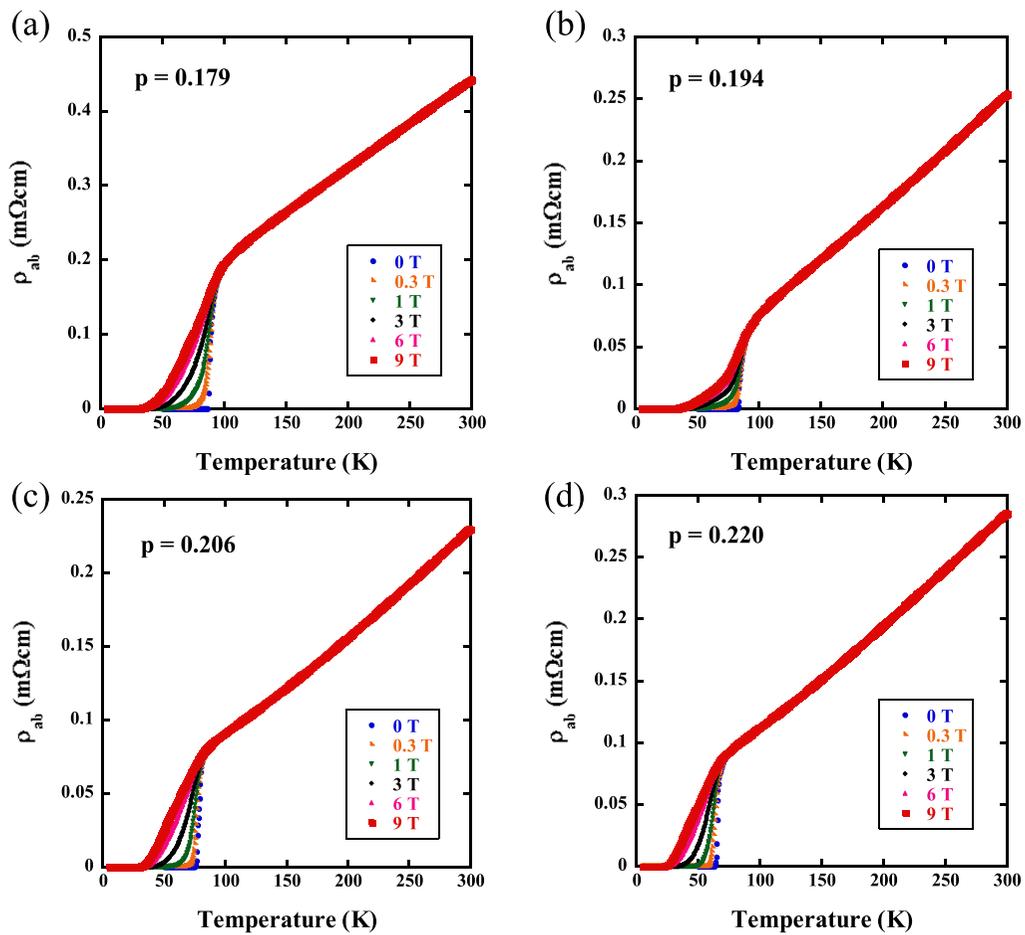


FIG. 5. In-plane resistivity $\rho_{ab}(T)$ for $\text{Bi}_{1.6}\text{Pb}_{0.4}\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$ single crystals under various magnetic fields $B \parallel c$ with (a) $p = 0.179$, (b) $p = 0.194$, (c) $p = 0.206$, and (d) $p = 0.220$, respectively.

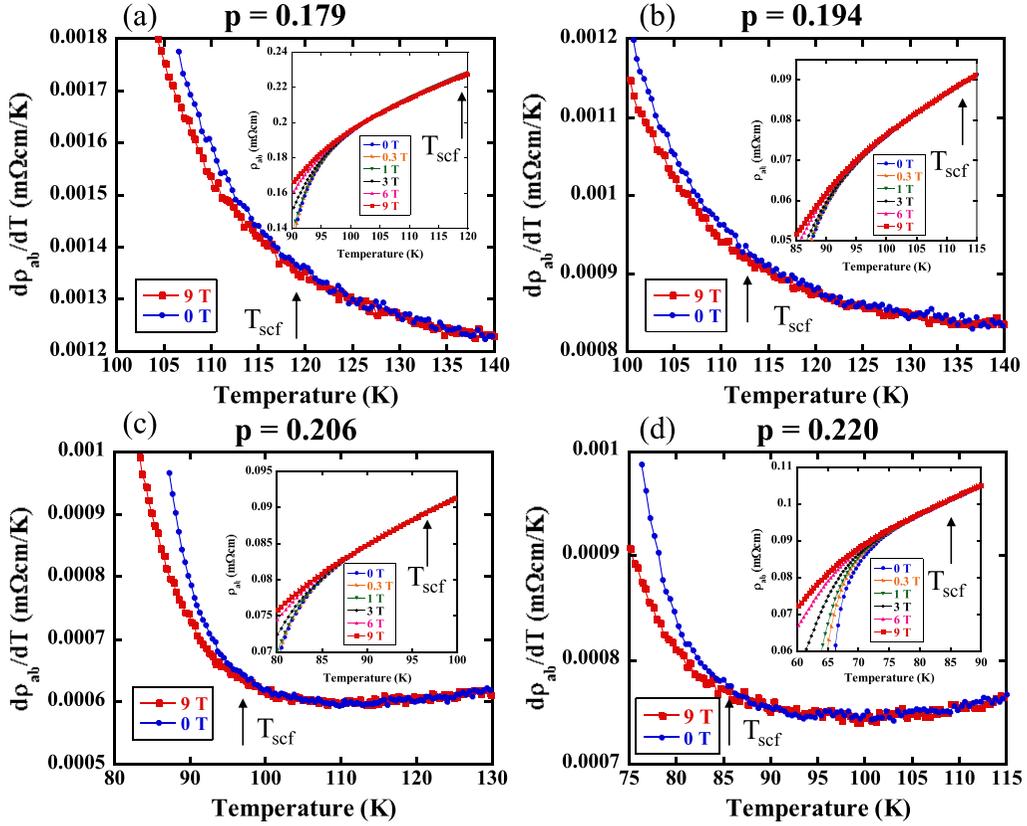


FIG. 6. Temperature derivative of ρ_{ab} vs the temperatures at 0 and 9 T for (a) $p = 0.179$, (b) $p = 0.194$, (c) $p = 0.206$, and (d) $p = 0.220$. The temperatures T_{scf} below which $d\rho_{ab}/dT$ at 9 T deviates from that at 0 T are indicated by arrows. The inset shows an expanded plot of ρ_{ab} vs temperature near T_c under various magnetic fields up to 9 T.

with increasing p , ensuring the increase in hole concentration with p . The temperature dependence of $R_H(T)$ decreases with increasing p , which agrees with previous studies on LSCO [34], Tl-2201 [35], and BSLCO [26]. Then, combining the results of Figs. 5 and 7, Hall mobility $\mu(T)$ is estimated. Figures 8(a)–8(d) show $\mu^{-1}(T)$ as a function of T^2 for the

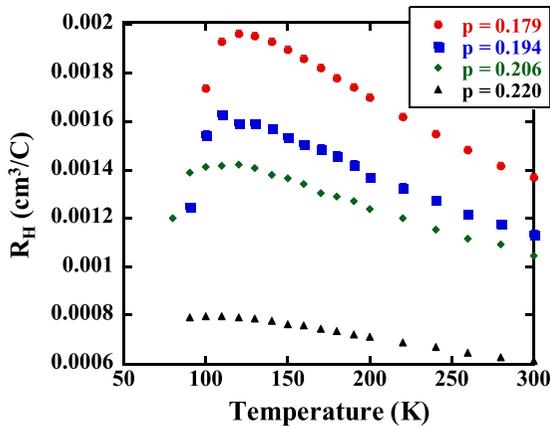


FIG. 7. Hall coefficient $R_H(T)$ for $\text{Bi}_{1.6}\text{Pb}_{0.4}\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$ single crystals with various p . The red solid circles, blue solid squares, green solid diamonds, and black solid up-pointing triangles represent data points for $p = 0.179$, 0.194, 0.206, and 0.220, respectively.

samples with $p = 0.179$, 0.194, 0.206, and 0.220, respectively. In all figures, $\mu^{-1}(T)$ roughly obeys the empirical $\propto T^2$ relation [36–39] at higher temperatures above 200 K, whereas it slightly deviates downward below 200 K, indicating that, below 200 K, μ is larger than the values that extrapolated high temperature values to low temperatures using the relation, $\mu \propto T^{-2}$. This implies that the electronic system acquires coherence below 200 K. Based on this observation, $T_{coh}\mu$ is defined as the temperature at which linearly fitted lines above and below 200 K intersect. Consequently, $T_{coh}\mu$ is estimated as 221, 217, 215, and 214 K for $p = 0.179$, 0.194, 0.206, and 0.220, respectively. It should be noted that similar deviation from high-temperature $\propto T^2$ behaviors at lower temperatures have been reported for the Hall angle $\cot\theta_H$ (a quantity similar to μ^{-1}) of overdoped cuprates [26,34], although the authors of Refs. [26] and [34] did not interpret this deviation as evidence for electronic coherence.

IV. PHASE DIAGRAM

The characteristic temperatures T_{coh} , $T_{\rho_c}^*$, $T_{\rho_c}^{**}$, $T_{\rho_{ab}}^{**}$, and T_{scf} are plotted as functions of p in Fig. 9. The plots show that $T_{coh}\rho_{ab}$ and $T_{coh}\mu$ coincide, which indicates that both have the same origin (i.e., from incoherent to coherent crossover temperatures). Based on this, we interpret T_{coh} as representing $T_{coh}\rho_{ab}$ and $T_{coh}\mu$ collectively. The plots also show that $T_{\rho_c}^{**}$ and $T_{\rho_{ab}}^{**}$ coincide, which indicates again that both have the same origin (i.e., the “strong” pseudogap opening). The rapid

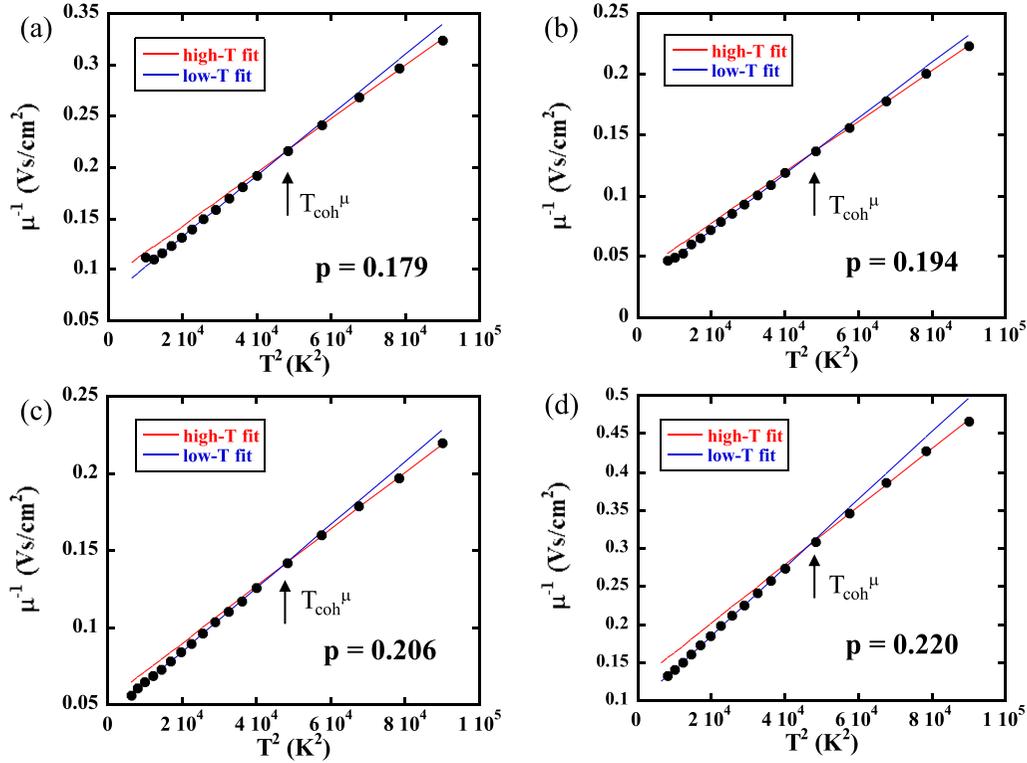


FIG. 8. Inverse Hall mobility μ^{-1} vs T^2 for $\text{Bi}_{1.6}\text{Pb}_{0.4}\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$ single crystals with (a) $p = 0.179$, (b) $p = 0.194$, (c) $p = 0.206$, and (d) $p = 0.220$. The red straight lines denote high-temperature linear fits between 220 and 300 K. The blue straight lines denote low-temperature linear fits between (a) 120 and 190 K, (b) 110 and 190 K, (c) 110 and 190 K, and (d) 90 and 190 K, respectively. $T_{\text{coh}}\mu$ at which the high-temperature and low-temperature linear fits intersect are indicated by arrows.

decrease in $\rho_{ab}(T)$ below $T_{\rho_{ab}}^{**}$ may be due to the decreasing scattering rate upon opening of the strong pseudogap. On this basis, we denote T^{**} as representing $T_{\rho_c}^{**}$ and $T_{\rho_{ab}}^{**}$ collectively. For $p \leq 0.19$, T^{**} differs from T_{scf} , whereas for $p > 0.19$,

T^{**} rapidly approaches T_{scf} , and eventually coincides with it at $p \approx 0.21$.

Next, we discuss the end point p^* of the weak pseudogap. Figure 9 shows that $T_{\rho_c}^*$ decreases rapidly for $p > 0.22$, and then disappears at $p \approx 0.23$. This result suggests that $p^* \approx 0.23$ for the Bi-2212 case. As discussed in Fig. 3(c), we observed a kink in the T^2 coefficient α_2 of $\rho_{ab}(T)$ at $p = 0.22$, where Lifshitz transition occurs [27]. Then, the disappearance for $T_{\rho_c}^*$ at $p \approx 0.23$ may be attributed to this Lifshitz transition, since the spectral weights at antinodal directions, which are needed to open the weak pseudogap, are expected to decrease after the transition [28].

Finally, in this section, we demonstrate the positional relationship between T_{coh} and $T_{\rho_c}^*$. Figure 9 shows that T_{coh} is independent of the doping level, with a slight tendency to decrease with excessive overdoping. T_{coh} seems to exist even below $p = 0.19$, since $T_{\text{coh}}\mu$ can be defined at $p = 0.179$ [Fig. 8(a)], although the change in $d\rho_{ab}/dT$ above and below $T_{\text{coh}}\rho_{ab}$ is insignificant for $p < 0.19$ (see the Supplemental Material [23]). This insignificance may be attributed to the fact that the feature accompanied by electronic coherence is masked by the incipient strong pseudogap opening. In fact, $T_{\text{coh}}\rho_{ab}$ can be seen more clearly in BSLCO for $0.16 \leq p \leq 0.18$ [40]. [In Fig. 1(b) of Ref. [40], with decreasing temperatures across $T_{\text{coh}}\rho_{ab} \approx 200$ K, the thin red colored region evolves into the thick colored region representing that $d^2\rho_{ab}/dT^2$ is enhanced upon cooling.] This may be due to the fact that in BSLCO, T^{**} is lower (< 100 K) than that in

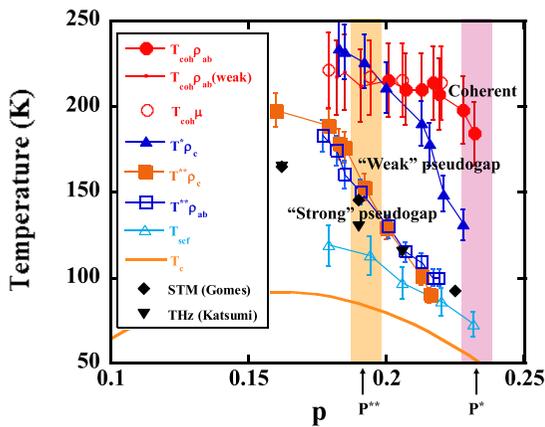


FIG. 9. Characteristic temperatures vs p for $\text{Bi}_{1.6}\text{Pb}_{0.4}\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$ and $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$ [20] single crystals. The black closed diamonds represent the pseudogap opening temperatures obtained by scanning tunneling microscopy (STM) [41] and down-pointing triangles represent those obtained by terahertz (THz) pump-optical probe spectroscopy [42]. The orange and purple bands indicate the characteristic doping levels of $p^{**} \approx 0.19$ and $p^* \approx 0.23$, respectively.

Bi(Pb)-2212. [In Fig. 1(b) of Ref. [40], T^{**} in our definition is depicted as the white band between the red and blue region for $0.16 \leq p \leq 0.18$.] Thus the feature accompanied by electronic coherence was not masked in BSLCO. We note strong correlations of these observations for BSLCO with those of $\cot\theta_H(T)$. This means that in BSLCO, $\cot\theta_H(T)$ shows marked deviation from the empirical $\propto T^2$ relation in the overdoped state [26], which agrees with our identification of T_{coh} . Based on these results, we conclude that $T_{\rho_c}^*$ and T_{coh} intersect at $p = 0.19$.

V. DISCUSSION

Here, we discuss the implications of the obtained results. First, we accurately determined the characteristic temperatures of two types of pseudogaps ($T_{\rho_c}^*$ and T^{**} for the weak and strong pseudogaps, respectively) by combining results from in-plane and out-of-plane transport measurements (Fig. 9). Then, we showed that T^{**} differed for T_{scf} for $p \leq 0.19$, while they coincided for $p > 0.19$. Based on this result, we considered that the strong pseudogap originated from preformed Cooper pairing (phase-incoherent Cooper pair formation) in the QCP model [Fig. 1(a)] or from spinon pairing in the RVB model [Fig. 1(b)]. Although several studies have reported preformed Cooper pairing in high- T_c cuprates [41–52], a general consensus has not been realized [7]. Furthermore, the doping levels for which these distinct pseudogaps terminate are unknown. We showed that T^{**} ends (or merges with T_{scf}) at approximately $p^{**} = 0.19$, whereas $T_{\rho_c}^*$ ends at approximately $p^* = 0.23$ for Pb-doped Bi-2212. Given that p^* of $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$ is 0.19 [53], it may be material (i.e., band structure) dependent [28].

Next, we found that $T_{\rho_c}^*$ and T_{coh} cross each other at $p^{**} = 0.19$. This behavior is incompatible with the conventional QCP scenario Fig. 1(a) [2,3]. Instead, our results favor the RVB scenario [Fig. 1(b)]. In the QCP scenario, T^* represents the temperatures of the phase transition [2,3], whereas in the RVB model, $T_D(T_D^{(0)})$ represents crossover temperatures from the strange metal to the pseudogap (spin gap to be precise) states [4–6]. In recent years, several phase transitions with symmetry breaking have been observed using various techniques in the pseudogap regime [54–63], which may support the QCP scenario. We encountered a serious problem on reconciling these observations with our results, which is currently an open question. In this regard, Hussey argued that such phase transitions do not form a pseudogap, but instead involve the development of electronic instability inside the pseudogap regime [64]. Tallon and Loram argued that the pseudogap reflects an underlying energy scale E_g that vanishes beneath the superconducting dome [16]. The energy scale may correspond to the superexchange energy J and provide the crossover temperatures. Thus, we assumed that $T_{\rho_c}^*$ corresponds to $T_D^{(0)}$ of the RVB model [4–6].

The strong pseudogap effect has been predicted using theories based on the Fermi-liquid point of view, which considers the effect of large antiferromagnetic spin fluctuations in quasi-two-dimensional metals near the Mott insulator [65–67]. In the RVB model, the strong pseudogap effect may be attributed to spinon pairing below T_D [4–6]. Furthermore, T_{coh} may correspond to the temperatures for Bose condensation of holons, T_{BE} , in the RVB model [6]. In this model, T_{BE} is proportional

to the superfluid density $\rho_s(0)$. Our result of approximately doping-independent T_{coh} in the overdoped region agrees with experimental observation for $\rho_s(0)$ [68]. Consequently, our observed phase diagram (Fig. 9) roughly coincides with the prediction of the RVB model [Fig. 1(b)].

It is intriguing to note that this normal state crossing phenomena of $T_{\rho_c}^*$ and T_{coh} influences the nature of superconducting fluctuations. When $T_{\rho_c}^* < T_{\text{coh}}$ for $p > 0.19$, the phase ordering of Cooper pairs starts to develop almost simultaneously as they form below $T^{**} \approx T_{\text{scf}}$. When $T_{\rho_c}^* > T_{\text{coh}}$ for $p < 0.19$, Cooper pairs are preformed below T^{**} , but their phases are not settled. Thus, superconducting fluctuation does not appear until lower values of T_{scf} . This nonsuperconducting behavior between T_{scf} and T^{**} when $p < 0.19$ is consistent with the spinon pairing in the RVB model [4–6]. In addition, with decreasing p below 0.19, $T_{\rho_c}^*$ and T_c increase. This result implies that the pseudogap does not just compete with superconductivity, but reflects the energy scale J , which is probably the source for superconductivity.

Although our data are incompatible with the conventional QCP scenario, $p^{**} = 0.19$ may be an anomalous critical point. In this study, we found that $T_{\rho_c}^*$ and T_{coh} cross at p^{**} , and the preformed nature for Cooper pairing changes over this doping level. Therefore, $p^{**} = 0.19$ is closely related to superconductivity and may be universal for hole-doped cuprates [16,64]. This anomalous criticality at p^{**} was proposed by Tallon and Loram [53].

Here, we assumed Eq. (1) and the incoherent to coherent crossover at $T_{\text{coh}} \approx 200$ K to interpret the temperature dependence of $\rho_{ab}(T)$. Alternatively, the power law formula may also reproduce the observed $\rho_{ab}(T)$ [69]. Another interpretation may be the achievement of the quantum mechanical constraint for the maximum scattering rate (Planckian dissipation limit) [13,64,70].

VI. SUMMARY

In this study, we clarified the true phase diagram for the overdoped side of high- T_c cuprates. The frequently discussed critical doping level, $p^{**} = 0.19$, is a doping level above which T_{coh} can be observed clearly, and the characteristic temperature of the opening of the strong pseudogap, T^{**} , approaches T_{scf} rapidly. These results agree with the RVB scenario, rather than the conventional QCP scenario. However, an anomalous QCP scenario cannot be ruled out. To complete the phase diagram, our approach must be extended to the underdoped side.

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